

November 1990

#### Features

- Performs ASK (amplitude shift keyed) modulation and demodulation
- 32 kHz carrier frequency
- Up to 2 kbit/s full duplex data transfer rate
- On-chip oscillator
- On-chip tone caller for alerting functions
- Adjustable tone caller frequencies
- Selectable self-loop test mode
- 5V/2.5mA power supply
- ISO<sup>2</sup>-CMOS and switched capacitor technologies
- 18 Pin DIP

# Applications

- Simultaneous data and voice communication in PABXs
- 2 kbit/s data modem
- "Smart" telephone sets

ISSUE 4 Ordering Information

MT8840AE 18 Pin Plastic DIP MT8840AS 18 Pin SOIC 0°C to +85°C

## Description

The MT8840 is a carrier over voice modem which allows simultaneous transfer of voice and data over a single pair of wires. Data is transferred on an amplitude shift keyed (ASK) 32 kHz carrier. On-chip filters remove voice frequency signals from the received composite voice and data signal prior to demodulation. The modulating signal is a bit stream with a typical data rate of 2 kbit/s. In addition, the device contains a two tone warbler which functions as a telephone ringer. The device is fabricated in MITEL's double-poly ISO<sup>2</sup>-CMOS technology utilizing switched-capacitor techniques.

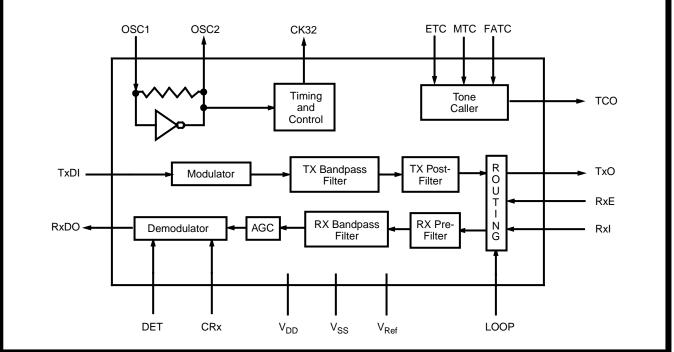


Figure 1 - Functional Block Diagram

DET CRx RxI LOOP VRef TxO TxD VSS	1 2 3 4 5 6 7 8 9		17 16 15 14 13 12 11	VDD RxDO OSC2 OSC1 CK32 ETC MTC TCO FATC
<u>18 F</u>	PIN PL	ASTIC	DIP/SO	IC

## Figure 2 - Pin Connections

# **Pin Description**

Pin #	Name	Des	cription				
1	DET	Demodulator detection level adjust input (Analog). Internal resistor divider applies 2.36V in open circuit condition. Connection of external resistor will vary detect level.					
2	CRx	External AGC time constant adjust input (	Analog). Connect external capacitor to $V_{SS}$ .				
3	RxI	Modulated receive signal input (Analog).	Biased at V <sub>Ref</sub> .				
4	RxE	Receive enable input (Digital) with interna	l pull up. Active high.				
5	LOOP	Self-test mode select input (Digital) with in	nternal pull down. Active high.				
6	V <sub>Ref</sub>	Internal reference supply voltage input (Analog) .					
7	TxO	Modulated transmit carrier output (Analog).					
8	TxDI	Transmit data input (Digital).					
9	V <sub>SS</sub>	Negative power supply.					
10	FATC	Tone caller center frequency adjust input (	Tone caller center frequency adjust input (Analog).				
11	TCO	Tone caller output (Digital).	Tone caller output (Digital).				
12	MTC	Mute tone caller input (Digital) with interna	al pull down. Active high.				
13	ETC	Enable tone caller input (Digital) with inter	nal pull down. Active high.				
14	CK32	32 kHz data strobe output (Digital).					
15	OSC1	Clock Input	3.579545 MHz crystal connected between				
16	OSC2	Clock Output to drive external devices.	these pins completes internal oscillator.				
17	RxDO	Receive data output (Digital). Synchronize	ed to CK32.				
18	V <sub>DD</sub>	Positive power supply.					

#### **Functional Description**

The MT8840 contains the modulator and demodulator circuitry for 32 kHz ASK signalling as well as a two-tone warbler (tone caller) to replace the function of the mechanical telephone ringer.

A 32 kHz carrier is 100% amplitude modulated by the digital bit stream applied to input TxDI. This results in an amplitude shift keyed (ASK) 32 kHz carrier. A logical high at TxDI disables the carrier and a logical low enables it. The digitally modulated waveform is shaped by the Tx BANDPASS FILTER and smoothed by the Tx POST FILTER. The signal then enters the routing block where it is transferred to the TxO output.

The modulated 32 kHz receive signal is applied to RxI. With a logical low applied to LOOP and a logical high applied to RxE, receive signals are routed to the Rx PREFILTER. High frequencies are removed by the Rx PREFILTER to prevent aliasing in the switched capacitor Rx BANDPASS FILTER. Voice signals are removed by the bandpass filter which is followed by an AGC circuit. This provides a dynamic range of 20dB for the receiver. An external 1µF capacitor connected from CRx to V<sub>SS</sub> is required to control the AGC attack and decay time constants. Data is recovered from the received signal in the demodulator. The minimum voltage level to which the demodulator responds may be adjusted bv connecting a resistor from DET to V<sub>DD</sub> or V<sub>Ref</sub>. Since DET is the input to a comparator, noise should be kept to a minimum at this pin. The recovered receive data is synchronized to the leading edge of the 32 kHz clock (available at CK32) before appearing at RxDO.

When in loop around mode, the Rx PREFILTER input is internally disconnected from the RxI input pin and connected to TxO. The transmitter output is still available at TxO.

A two tone warbling audio signal is available at TCO when the tone caller enable input (ETC) is high. TCO is internally clamped to  $V_{Ref}$  when the tone caller is disabled. The tone output can be attenuated by 20dB if a logical high is applied to the tone caller mute input (MTC).

#### Applications

Figures 3 through 5 show how the MT8840 may be utilized to transfer data and voice simultaneously over a single pair of wires in digital or analog PABXs and "smart" telephone sets. In all three figures a microprocessor sends/receives data to/from the MT8840 via a UART which converts the data format from parallel-to-serial or serial-to-parallel for the transmit and receive directions, respectively. In the receive direction the MT8840 has on-board filters to reject voice-band signals leaving only the 32 kHz carrier. This carrier is then demodulated to recover the received data. In the transmit direction the data to be sent is modulated and passed on to a summing circuit which sums the modulated 32 kHz carrier and voiceband signals for transmission over the telephone line. In the PABX the Filter/Codec has filters which reject the 32 kHz carrier from the received composite voice and data signal allowing only voiceband signals to pass through which are then PCM encoded for digital switching. However, in both the analog PABX and smart telephone set, lowpass filters could be included to bandlimit the received signal leaving only voice signals to be passed on to the switch array or handset earpiece.

# MT8840 ISO<sup>2</sup>-CMOS

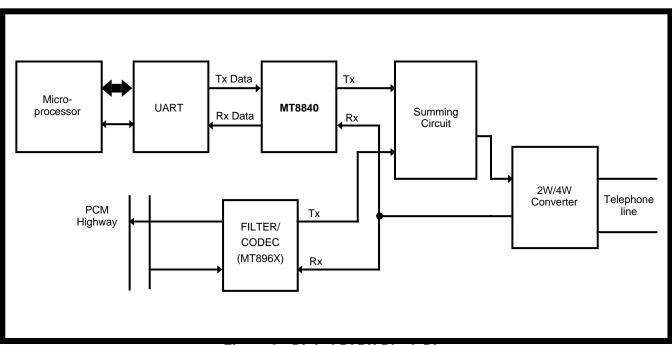
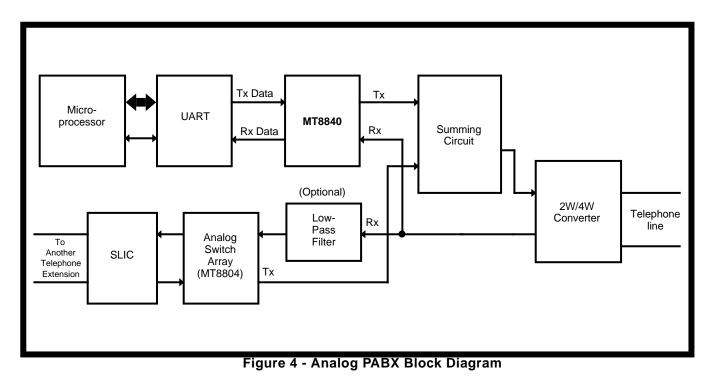


Figure 3 - Digital PABX Block Diagram



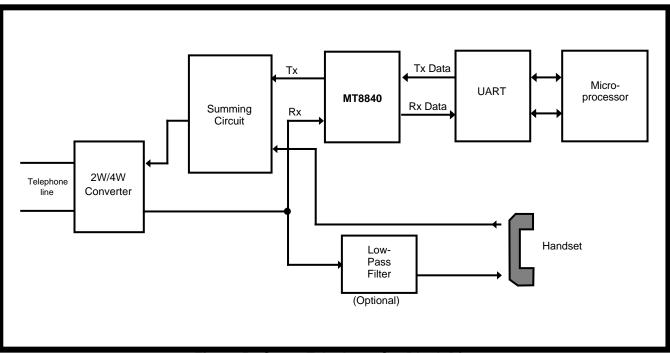


Figure 5 - Smart Telephone Set Block Diagram

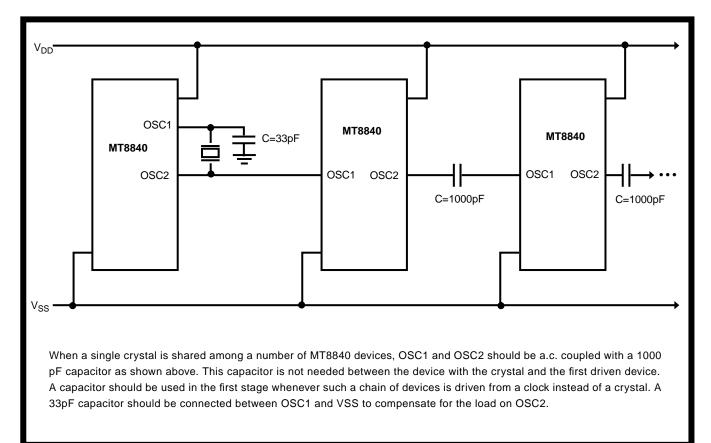


Figure 6 - Crystal Oscillator Connections for Driving Multiple MT8840s

# **Absolute Maximum Ratings\***

	Parameter	Symbol	Min	Max	Unit
1	Supply Voltage	V <sub>DD</sub> -V <sub>SS</sub>	-0.3	+7.0	V
2	Voltage On Any Pin	V <sub>Max</sub>	V <sub>SS</sub> -0.3	V <sub>DD</sub> +0.3	V
3	Current On Any Pin	I <sub>Max</sub>		20	mA
4	Storage Temperature	Τ <sub>S</sub>	-65	+150	°C
5	Package Power Dissipation	P <sub>Diss</sub>		850	mW

\* Exceeding these ratings may cause permanent damage. Functional operation under these conditions is not implied.

# **Recommended Operating Conditions**

	Parameter	Symbol	Min	Тур	Max	Unit
1	Operating Supply Voltages	V <sub>DD</sub>	4.75	5	5.25	V
2		V <sub>Ref</sub>		0.4V <sub>DD</sub>		V
3	Operating Supply Currents	I <sub>DD</sub>		2.5	5.0	mA
4		I <sub>Ref</sub>			200	μA
5	Operating Temperature	Т <sub>О</sub>	0		+85	°C
6	Load Capacitance (TxO)	CL			50	pF
7	Load Resistance (TxO)	RL	10			KΩ

# **D.C. Characteristics** - $V_{DD} = 5.0 \text{ V} \pm 5\%$ V<sub>SS</sub> =0V T = 0 - 85°C (All voltages are referenced to V<sub>SS</sub> /GND)

		Characteristics	Sym	Min	Тур	Max	Unit	Test Conditions
1		Input Current	I <sub>IN</sub>			±10	μA	$V_{IN} = 0$ to $V_{DD}$
2	D	Input Low Voltage	V <sub>IL</sub>	0		1.5	V	
3	G	Input High Voltage	VIH	3.5		5.0	V	
4	Ι	Output Low Voltage	V <sub>OL</sub>			0.4	V	I <sub>OL</sub> = 0.4mA
5	T A	Output High Voltage	V <sub>OH</sub>	4.6			V	I <sub>OH</sub> = 0.4mA
6	Ĺ	Output Drive Current						
7		N Channel Sink (Except OSC2)	I <sub>OL</sub>	0.4			mA	$V_{OL} = 0.4V$
8	1	OSC2		0.1			mA	
9	ó	P Channel Source (Except OSC2)	I <sub>OH</sub>	0.4			mA	V <sub>OH</sub> = 4.6V
10		OSC2		0.1			mA	
11		Input Current (RxI, FATC)	I <sub>IN</sub>			±10	μΑ	$V_{IN} = 0$ to 5.0V
12		Input Resistance (FATC)	R <sub>IN</sub>	500			KΩ	
13	А	(DET to V <sub>DD</sub> )			170		KΩ	
14	N	(DET to V <sub>Ref</sub> )			23		KΩ	
15	A L	Input Capacitance (RxI)	C <sub>IN</sub>		50		pF	
16	ō	(FATC)			10		pF	
17	G	Any Digital Input			5.0	7.5	pF	
18	I	Output Resistance (TxO)	R <sub>O</sub>		100		Ω	
19	/	(TCO)			3		KΩ	MTC = 0
20	0	(TCO)			30		KΩ	MTC = 1
21		Output Offset Voltage (TxO)	Vo		±25	±200	mV	
22		Output Voltage (DET)	Vo	2.20	2.36	2.55	V	See Note 1

Notes: 1. Voltage specified is generated internally and measured with no external components connected to DET

		Characteristics	Sym	Min	Тур	Max	Unit	Test Conditions
1		Crystal/Clock Frequency	f <sub>C</sub>	3.5759	3.5795	3.5831	MHz	OSC1, OSC2
2		Clock Input (OSC 1)						
3		Rise Time	t <sub>LHCI</sub>			100	ns	10% - 90% of (V <sub>DD</sub> - V <sub>SS</sub> )
4	D	Fall Time	t <sub>HLCI</sub>			100	ns	
5		Duty Cycle	DC <sub>CI</sub>	40	50	60	%	
6	G	Clock Output (OSC 2)	0.					
7		Rise Time	t <sub>LHCO</sub>		100		ns	C <sub>1</sub> = 30pF, 3.58MHz ext.
8	A	Fall Time	t <sub>HLCO</sub>		100		ns	clock to OSC1
9	L	Duty Cycle	DC <sub>CO</sub>		50		%	
10		Capacitive Load	C <sub>LCO</sub>			30	pF	
11		Clock Output (CK32)	F <sub>C32</sub>	32508	32541	32574	Hz	fc = 3.5795MHz
12	ó	Rise Time	t <sub>LH32</sub>		100		ns	10% - 90% of (V <sub>DD</sub> - V <sub>SS</sub> )
13		Fall Time	t <sub>HL32</sub>		100		ns	$C_L = 100 \text{pF}$
14		Duty Cycle	DC <sub>32</sub>		50		%	
15		Capacitive Load			00	100	pF	
16		Warbler Frequency (TCO)	C <sub>L32</sub> f <sub>W</sub>	7.935	7.945	7.955	Hz	fc = 3.5795MHz ± 0.1%
17		Low Tone Frequency		352	390	428	Hz	FATC = 0, $f_c$ = 3.5795MHz
18	Т		f <sub>LT</sub>	1036	1148	1260	Hz	FATC = $V_{DD}$ , $f_c$ = 3.5795MH
	0	Lligh Tong Fraguency	£	440	487	535	Hz	-
19	N E	High Tone Frequency	f <sub>HT</sub>					FATC = 0, $f_c$ = 3.5795MHz
20		Llange ania Dalatianakin	£ /£	1295	1434	1574	Hz	FATC = V <sub>DD</sub> , f <sub>c</sub> = 3.5795MH
21	С	Harmonic Relationship	f <sub>HT</sub> /f <sub>LT</sub>		1.25			
22	Α	Warbler Output (TCO)						
23		Rise Time	t <sub>LHWO</sub>		500		ns	100K $\Omega$ load to V <sub>Ref</sub>
24	E	Fall Time	t <sub>HLWO</sub>		500		ns	$C_L = 30 pF, MTC = 0$
25	R	Duty Cycle	DC <sub>WO</sub>		50		%	
26		Output Level (TCO)	V <sub>TCC</sub>		V <sub>DD</sub>		V <sub>pp</sub>	MTC = 0
27					0.625		V <sub>pp</sub>	MTC = 1 (100K $\Omega$ load to V <sub>Ref</sub> )
28	М	Modulated Frequency	f <sub>MOD</sub>		32541		Hz	
29	0	Output Level (TxO)	V <sub>TxO</sub>	225	250	270	mV <sub>pp</sub>	$V_{DD} = 5V$
30	D	Output Level (TxO)						
31	UL	variation vs. V <sub>DD</sub>	V <sub>TxO</sub>		100		%	
32	A	Transmit Data Input (TxDI)						
33	Т	Rise Time	t <sub>LHTxDI</sub>			100	ns	
34		Fall Time	t <sub>HLTxDI</sub>			100	ns	
35	R	Data Rate (TxDI)	f <sub>Data</sub>		2		k/bits	See Note 1
36	D	Input Impedance (RxI)	Z <sub>IN</sub>		50		KΩ	32 kHz Input Frequency
37	E	Valid Input Level - Data (RxI)	V <sub>RxI</sub>	40		400	mV <sub>pp</sub>	See Note 2
38	M O	Valid Input Level - Data + Voice	V <sub>RxI</sub>			3.0	V <sub>pp</sub>	
39	D	Receive Data Output (RxDO)	f <sub>Data</sub>		2		kbit/s	
40	UL	Rise Time			100		ns	10% - 90% of (V <sub>DD</sub> - V <sub>SS</sub> )
41	Ā	Fall Time			100		ns	C <sub>I</sub> = 100pF
42	T O	Capacitive Load				100	pF	
43	R	Duty Cycle		40	50	60	%	
otes	s	1. All A.C. parameters are based	l on a tvoi					1

A.C.	Characteristics -	• V <sub>DD</sub> =5.0V±5%	V <sub>SS</sub> =0V	T=0 - 85°C	(All voltages are referenced	to V <sub>SS</sub> /GND)
------	-------------------	----------------------------	---------------------	------------	------------------------------	--------------------------

# A.C. Characteristics (Continued)

		Characteristics	Sym	Min	Тур	Max	Unit	Test Conditions
44	D	Inband Noise Rejection (S/N)		12			dB	Input Sig. (RxI) = 400mV <sub>pp</sub>
45	E M	Attenuation to Voice Signals		40			dB	f <sub>in</sub> = 0 - 5KHz
46	O	Detect Filter Q	Q		3.8			
47	D	Detector Center Frequency			32		kHz	

Notes:

1. 2.

All A.C. parameters are based on a typical data rate of 2 kbit/s. Measured with no external resistor to DET input. Detection level internally set to 2.36V typical.